

# TC74VHCU04F, TC74VHCU04FN, TC74VHCU04FT

## Hex Inverter

The TC74VHCU04 is an advanced high speed CMOS INVERTER fabricated with silicon gate C<sup>2</sup>MOS technology.

It achieves the high speed operation similar to equivalent Bipolar Schottky TTL while maintaining the CMOS low power dissipation.

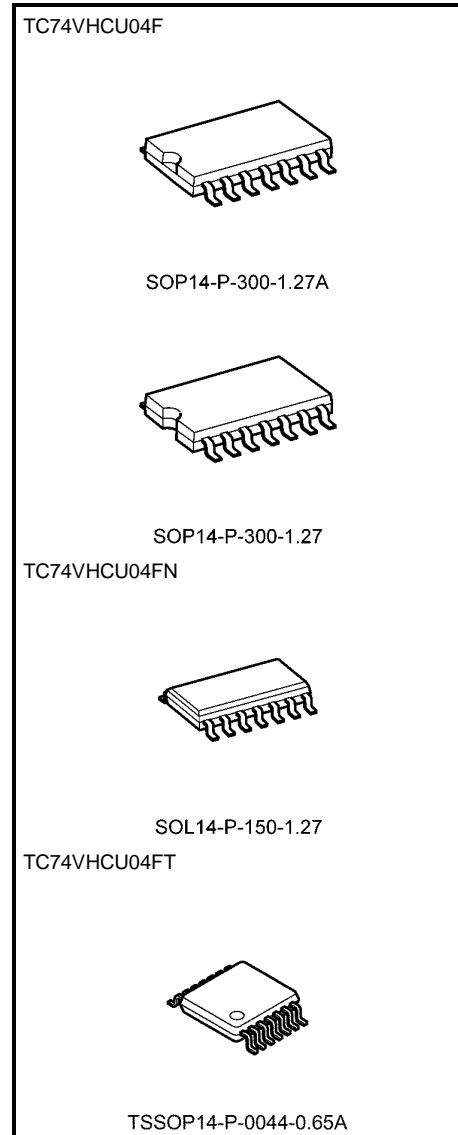
Since the internal circuit is composed of a single stage inverter, it can be used in analog applications such as crystal oscillators.

An input protection circuit ensures that 0 to 5.5 V can be applied to the input pins without regard to the supply voltage. This device can be used to interface 5 V to 3 V systems and two supply systems such as battery back up. This circuit prevents device destruction due to mismatched supply and input voltages.

### Features

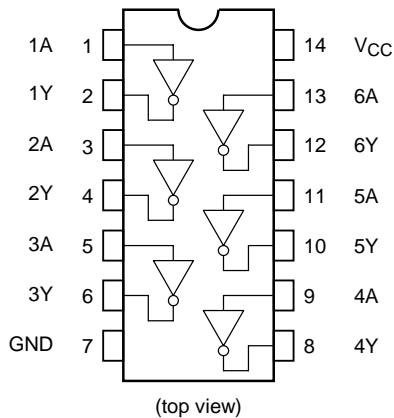
- High speed:  $t_{pd} = 3.5 \text{ ns}$  (typ.) at  $V_{CC} = 5 \text{ V}$
- Low power dissipation:  $I_{CC} = 2 \mu\text{A}$  (max) at  $T_a = 25^\circ\text{C}$
- High noise immunity:  $V_{NIH} = V_{NIL} = 10\% V_{CC}$  (min)
- Power down protection is provided on all inputs.
- Balanced propagation delays:  $t_{pLH} \approx t_{pHL}$
- Wide operating voltage range:  $V_{CC} (\text{opr}) = 2 \text{ V to } 5.5 \text{ V}$
- Low noise:  $V_{OLP} = 0.8 \text{ V}$  (max)
- Pin and function compatible with 74ALS04

Note: xxxFN (JEDEC SOP) is not available in Japan.

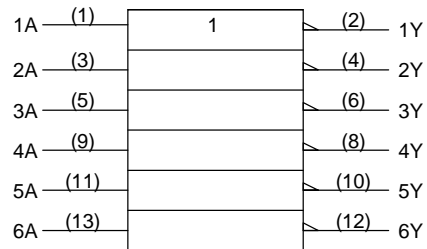


Weight	
SOP14-P-300-1.27A	: 0.18 g (typ.)
SOP14-P-300-1.27	: 0.18 g (typ.)
SOL14-P-150-1.27	: 0.12 g (typ.)
TSSOP14-P-0044-0.65A	: 0.06 g (typ.)

## Pin Assignment



## IEC Logic Symbol



## Truth Table

A	Y
L	H
H	L

## Absolute Maximum Ratings (Note)

Characteristics	Symbol	Rating	Unit
Supply voltage range	V <sub>CC</sub>	-0.5 to 7.0	V
DC input voltage	V <sub>IN</sub>	-0.5 to 7.0	V
DC output voltage	V <sub>OUT</sub>	-0.5 to V <sub>CC</sub> + 0.5	V
Input diode current	I <sub>IK</sub>	-20	mA
Output diode current	I <sub>OK</sub>	±20	mA
DC output current	I <sub>OUT</sub>	±25	mA
DC V <sub>CC</sub> /ground current	I <sub>CC</sub>	±50	mA
Power dissipation	P <sub>D</sub>	180	mW
Storage temperature	T <sub>stg</sub>	-65 to 150	°C

Note: Exceeding any of the absolute maximum ratings, even briefly, lead to deterioration in IC performance or even destruction.

## Recommended Operating Conditions (Note)

Characteristics	Symbol	Rating	Unit
Supply voltage	V <sub>CC</sub>	2.0 to 5.5	V
Input voltage	V <sub>IN</sub>	0 to 5.5	V
Output voltage	V <sub>OUT</sub>	0 to V <sub>CC</sub>	V
Operating temperature	T <sub>opr</sub>	-40 to 85	°C

Note: The recommended operating conditions are required to ensure the normal operation of the device. Unused inputs must be tied to either VCC or GND.

## Electrical Characteristics

### DC Characteristics

Characteristics	Symbol	Test Condition		Ta = 25°C			Ta = -40 to 85°C		Unit	
				V <sub>CC</sub> (V)	Min	Typ.	Max	Min		Max
High-level input voltage	V <sub>IH</sub>	V <sub>OUT</sub> = V <sub>OL</sub>		2.0 3.0 to 5.5	1.70 V <sub>CC</sub> × 0.8	— —	— —	1.70 V <sub>CC</sub> × 0.8	— —	V
Low-level input voltage	V <sub>IL</sub>	V <sub>OUT</sub> = V <sub>OH</sub>		2.0 3.0 to 5.5	— —	— —	0.30 V <sub>CC</sub> × 0.2	— —	0.30 V <sub>CC</sub> × 0.2	V
High-level output voltage	V <sub>OH</sub>	V <sub>IN</sub> = V <sub>IL</sub>	I <sub>OH</sub> = -50 μA	2.0	1.8	2.0	—	1.8	—	V
				3.0	2.7	3.0	—	2.7	—	
		V <sub>IN</sub> = GND	I <sub>OH</sub> = -4 mA I <sub>OH</sub> = -8 mA	3.0	2.58	—	—	2.48	—	
				4.5	3.94	—	—	3.80	—	
Low-level output voltage	V <sub>OL</sub>	V <sub>IN</sub> = V <sub>IH</sub>	I <sub>OL</sub> = 50 μA	2.0	—	0.0	0.2	—	0.2	V
				3.0	—	0.0	0.3	—	0.3	
		V <sub>IN</sub> = V <sub>CC</sub>	I <sub>OL</sub> = 4 mA I <sub>OL</sub> = 8 mA	3.0	—	—	0.36	—	0.44	
				4.5	—	—	0.36	—	0.44	
Input leakage current	I <sub>IN</sub>	V <sub>IN</sub> = 5.5 V or GND		0 to 5.5	—	—	±0.1	—	±1.0	μA
Quiescent supply current	I <sub>CC</sub>	V <sub>IN</sub> = V <sub>CC</sub> or GND		5.5	—	—	2.0	—	20.0	μA

### AC Characteristics (input: t<sub>r</sub> = t<sub>f</sub> = 3 ns)

Characteristics	Symbol	Test Condition		Ta = 25°C			Ta = -40 to 85°C		Unit	
				V <sub>CC</sub> (V)	C <sub>L</sub> (pF)	Min	Typ.	Max		Min
Propagation delay time	t <sub>pLH</sub>	—	3.3 ± 0.3	15	—	5.0	8.9	1.0	10.5	ns
				50	—	7.5	11.4	1.0	13.0	
	t <sub>pHL</sub>	—	5.0 ± 0.5	15	—	3.5	5.5	1.0	6.5	
				50	—	5.0	7.0	1.0	8.0	
Input capacitance	C <sub>IN</sub>	—		—	4	10	—	10	pF	
Power dissipation capacitance	C <sub>PD</sub>	(Note)		—	9	—	—	—	pF	

Note: C<sub>PD</sub> is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load.

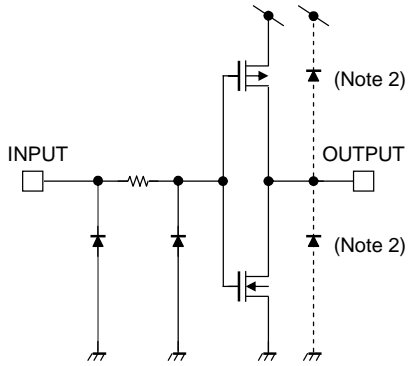
Average operating current can be obtained by the equation:

$$I_{CC (opr)} = C_{PD} \cdot V_{CC} \cdot f_{IN} + I_{CC}/6 \text{ (per gate)}$$

## Noise Characteristics (input: $t_r = t_f = 3 \text{ ns}$ )

Characteristics	Symbol	Test Condition	Ta = 25°C			Unit
			V <sub>CC</sub> (V)	Typ.	Max	
Quiet output maximum dynamic V <sub>OL</sub>	V <sub>OLP</sub>	C <sub>L</sub> = 50 pF	5.0	0.5	0.8	V
Quiet output minimum dynamic V <sub>OL</sub>	V <sub>OLV</sub>	C <sub>L</sub> = 50 pF	5.0	-0.5	-0.8	V
Minimum high level dynamic input voltage	V <sub>IHD</sub>	C <sub>L</sub> = 50 pF	5.0	—	4.0	V
Maximum low level dynamic input voltage	V <sub>ILD</sub>	C <sub>L</sub> = 50 pF	5.0	—	1.0	V

## Input Equivalent Circuit

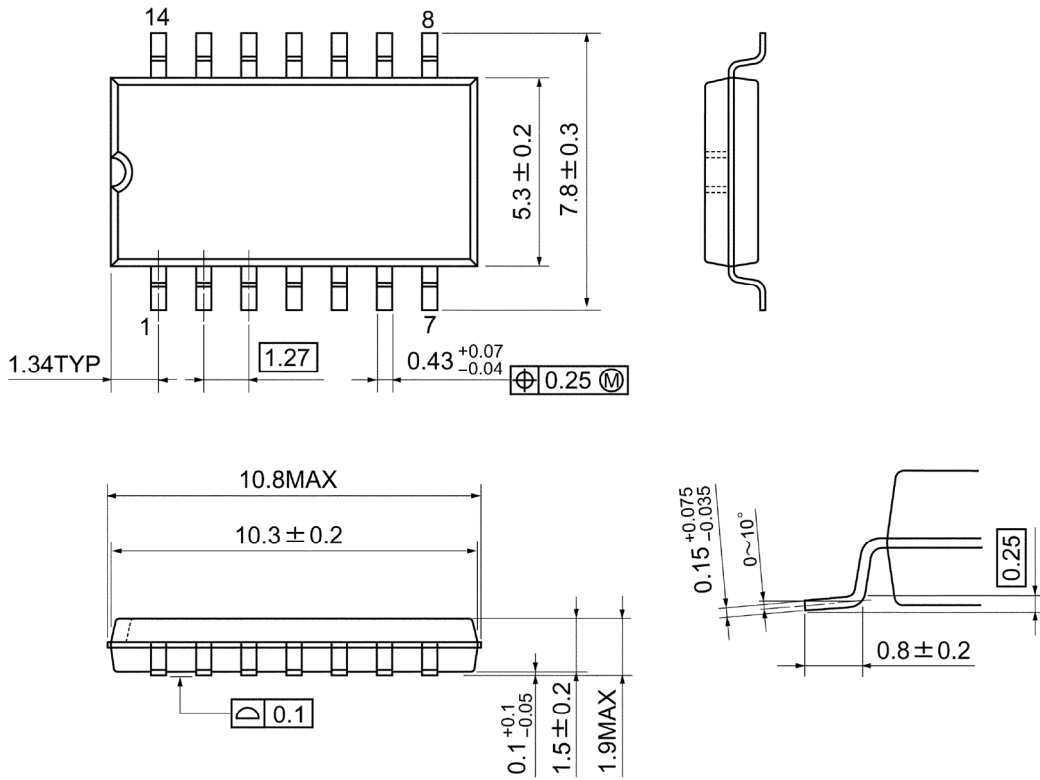


Note 2: Parasitic diode

## Package Dimensions

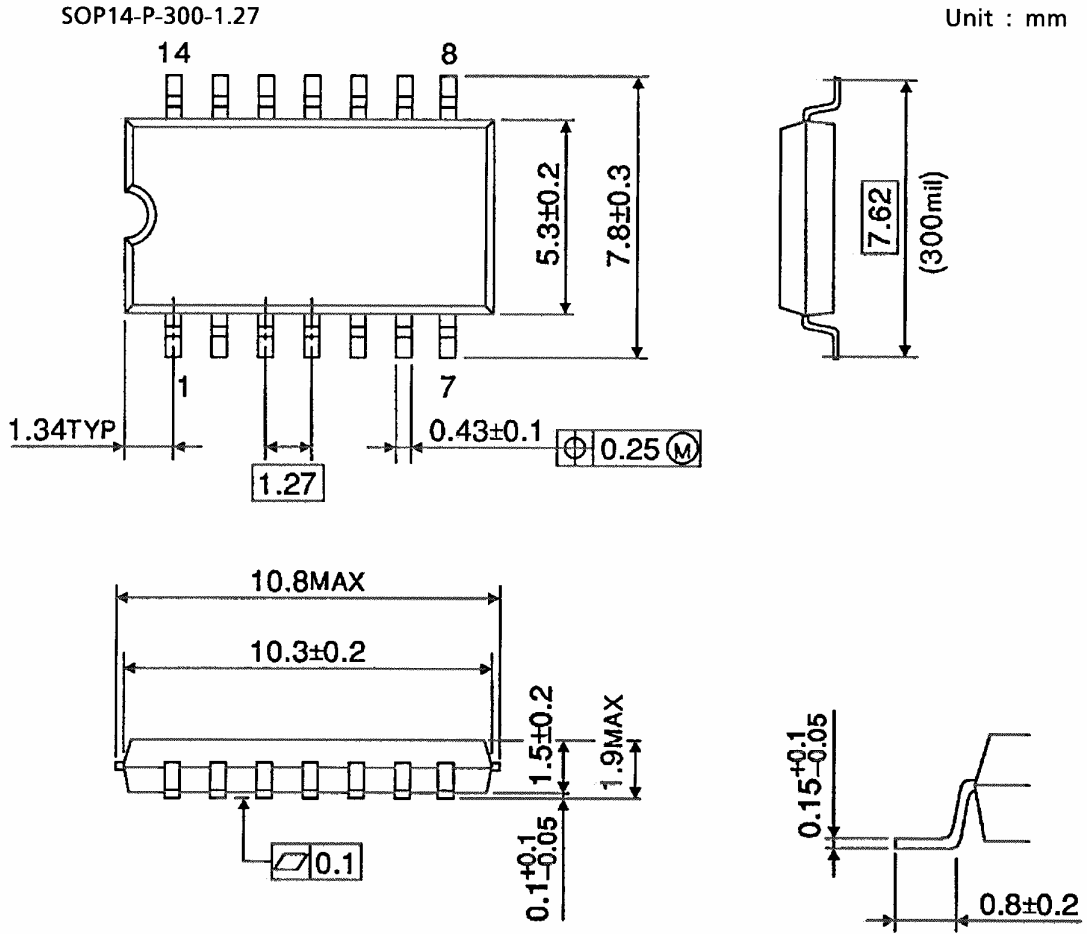
SOP14-P-300-1.27A

Unit: mm



Weight: 0.18 g (typ.)

**Package Dimensions**

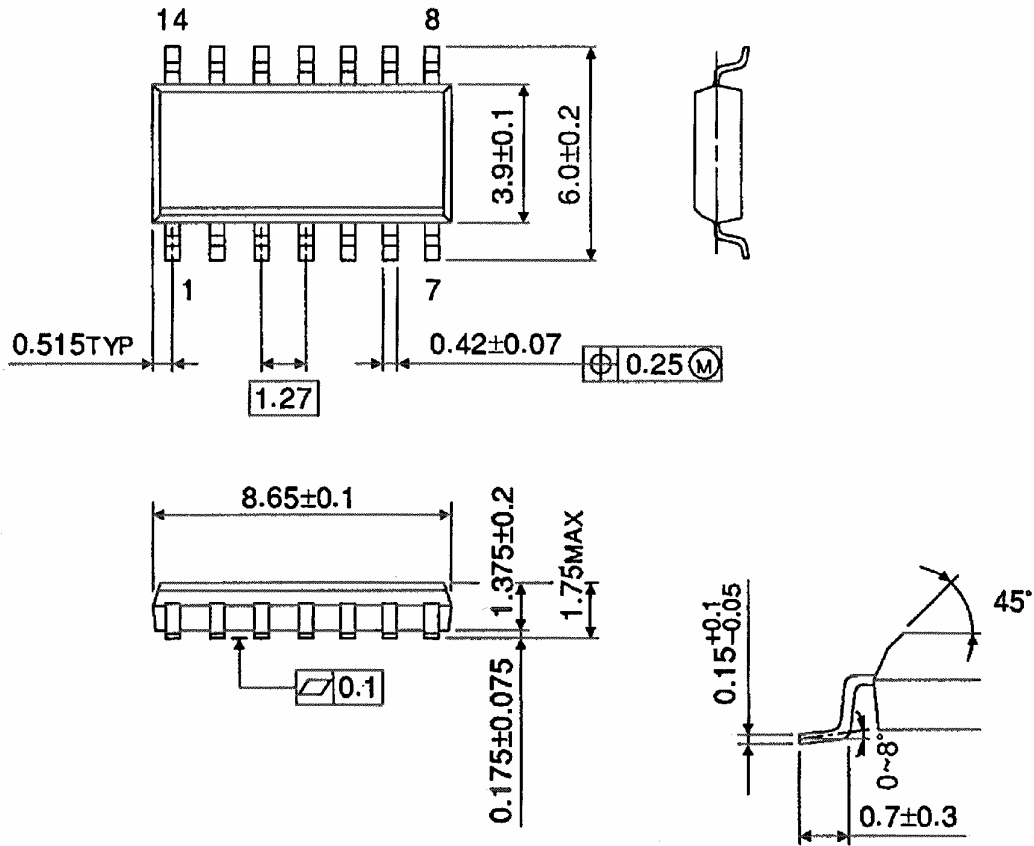


Weight: 0.18 g (typ.)

## Package Dimensions (Note)

SOL14-P-150-1.27

Unit : mm



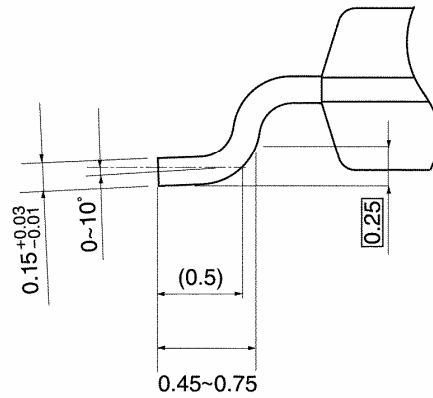
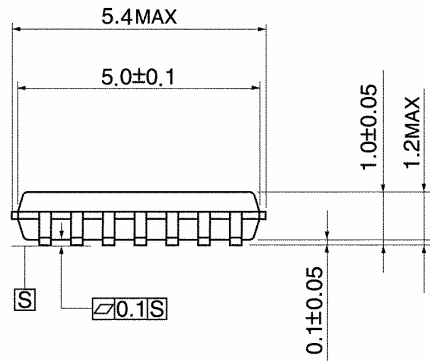
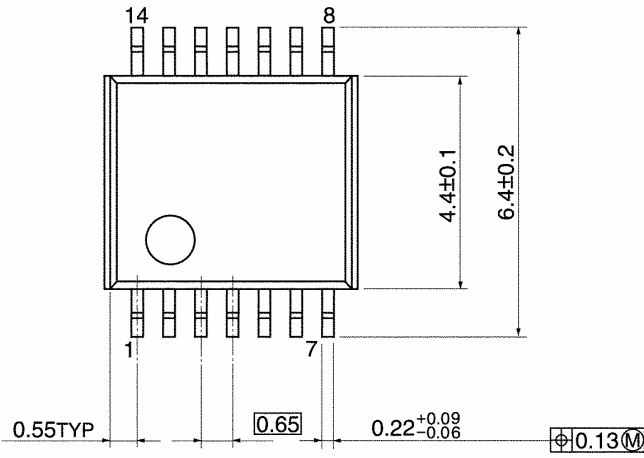
Note: This package is not available in Japan.

Weight: 0.12 g (typ.)

## Package Dimensions

TSSOP14-P-0044-0.65A

Unit: mm



Weight: 0.06 g (typ.)



**Note: Lead (Pb)-Free Packages****SOP14-P-300-1.27A SOL14-P-150-1.27 TSSOP14-P-0044-0.65A****RESTRICTIONS ON PRODUCT USE**

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